



N-Channel Power MOSFET

1000V, 1.85A, 8.5Ω

FEATURES

- 100% avalanche tested
- Advanced planar process
- Compliant to RoHS Directive 2011/65/EU and in accordance to WEEE 2002/96/EC
- Halogen-free according to IEC 61249-2-21

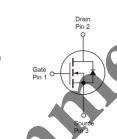
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11.41	III NS

- AC/DC LED Lighting
- Power Supply
- Power Meter

KEY PERFORMANCE PARAMETERS				
PARAMETER VALUE UNIT				
V_{DS}	1000	V		
R _{DS(on)} (max)	8.5	Ω		
Q_g	17	nC		







ABSOLUTE MAXIMUM RATINGS (T _A = 25°C unless otherwise noted)				
PARAMETER	SYMBOL	Limit	UNIT	
Drain-Source Voltage	V _{DS}	1000	V	
Gate-Source Voltage	V_{GS}	±30	V	
Continuous Drain Current (Note 1) T _C = 25°C	- I _D	1.85	А	
T _C = 100°C		1.16		
Pulsed Drain Current (Note 2)	I _{DM}	7.4	Α	
Total Power Dissipation @ T _C = 25°C	P _{DTOT}	77	W	
Single Pulse Avalanche Energy (Note 3)	E _{AS}	20	mJ	
Single Pulse Avalanche Current (Note 3)	I _{AS}	1.4	Α	
Operating Junction and Storage Temperature Range	T _J , T _{STG}	- 55 to +150	°C	

THERMAL PERFORMANCE				
PARAMETER	SYMBOL	Limit	UNIT	
Junction to Case Thermal Resistance	R _{eJC}	1.62	°C/W	
Junction to Ambient Thermal Resistance	$R_{\Theta JA}$	62	°C/W	

Thermal Performance Note: $R_{\Theta JA}$ is the sum of the junction-to-case and case-to-ambient thermal resistances. The case-thermal reference is defined at the solder mounting surface of the drain pins. $R_{\Theta JA}$ is guaranteed by design while $R_{\Theta CA}$ is determined by the user's board design. $R_{\Theta JA}$ shown below for single device operation on FR-4 PCB in still air.

1



ELECTRICAL SPECIFICATIONS (T _A = 25°C unless otherwise noted)						
PARAMETER	CONDITIONS	SYMBOL	MIN	TYP	MAX	UNIT
Static	Static					
Drain-Source Breakdown Voltage	$V_{GS} = 0V, I_D = 250\mu A$	BV _{DSS}	1000			V
Gate Threshold Voltage	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	$V_{GS(TH)}$	3.5	4.5	5.5	V
Gate Body Leakage	$V_{GS} = \pm 30 V$, $V_{DS} = 0 V$	I _{GSS}			±100	nA
Zero Gate Voltage Drain Current	$V_{DS} = 1000V, V_{GS} = 0V$	I _{DSS}			1	μΑ
Drain-Source On-State Resistance (Note 4)	$V_{GS} = 10V, I_D = 0.9A$	R _{DS(on)}		6	8.5	Ω
Dynamic (Note 5)		l			7	"
Total Gate Charge		Qg		17		
Gate-Source Charge	$V_{DS} = 800V, I_{D} = 1.85A,$	Q _{gs}	(5		nC
Gate-Drain Charge	$V_{GS} = 10V$	Q_{gd}		9		
Input Capacitance		C _{iss}	1	625		
Output Capacitance	$V_{DS} = 25V, V_{GS} = 0V,$ f = 1.0MHz	C _{oss}	<i>J '</i>	38		pF
Reverse Transfer Capacitance	1 = 1.0001112	C _{rss}		15		
Gate Resistance	f = 1.0MHz, open drain	R_g		2.2		Ω
Switching (Note 6)						
Turn-On Delay Time		t _{d(on)}		31		
Turn-On Rise Time	$V_{DD} = 500V, R_{G} = 25\Omega,$	t _r		14		
Turn-Off Delay Time	$I_D = 0.9A$, $V_{GS} = 10V$	$t_{d(off)}$		78		ns
Turn-Off Fall Time		t _f		44		
Source-Drain Diode						
Forward Voltage (Note 4)	$I_S = 1.85A, V_{GS} = 0V$	V _{SD}		-	1.4	V
Reverse Recovery Time	$V_R = 100V, I_S = 1.85A$	t _{rr}		359		ns
Reverse Recovery Charge	$dI_F/dt = 100A/\mu s$	Q_{rr}		1.34		μC

Notes:

- 1. Current limited by package
- 2. Pulse width limited by the maximum junction temperature
- 3. L = 20mH, I_{AS} = 1.4A, V_{DD} = 50V, R_G = 25 Ω , Starting T_J = 25 $^{\circ}C$
- 4. Pulse test: PW ≤ 300μs, duty cycle ≤ 2%
- 5. For DESIGN AID ONLY, not subject to production testing.
- 6. Switching time is essentially independent of operating temperature.

ORDERING INFORMATION

PART NO.	PACKAGE	PACKING
TSM2N100CH C5G	TO-251 (IPAK)	75pcs / Tube

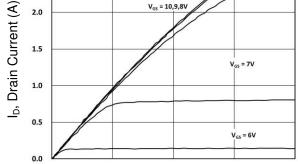


CHARACTERISTICS CURVES

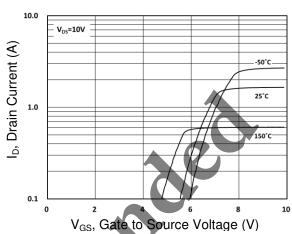
(T_C = 25°C unless otherwise noted)

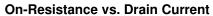
2.5 2.0

Output Characteristics

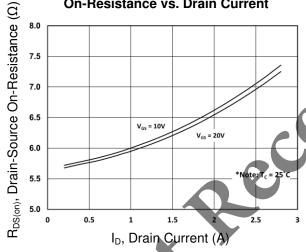


Transfer Characteristics

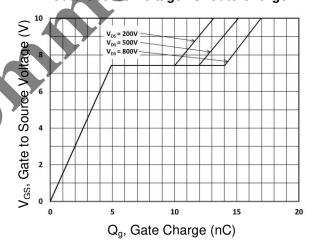




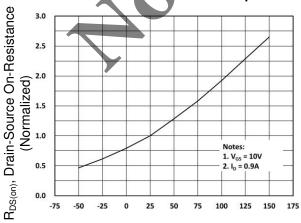
V_{DS}, Drain to Source Voltage (V)



Gate-Source Voltage vs. Gate Charge

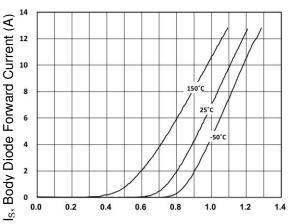


On-Resistance vs. Junction Temperature



T_J, Junction Temperature (°C)

Source-Drain Diode Forward Current vs. Voltage



V_{SD}, Body Diode Forward Voltage (V)



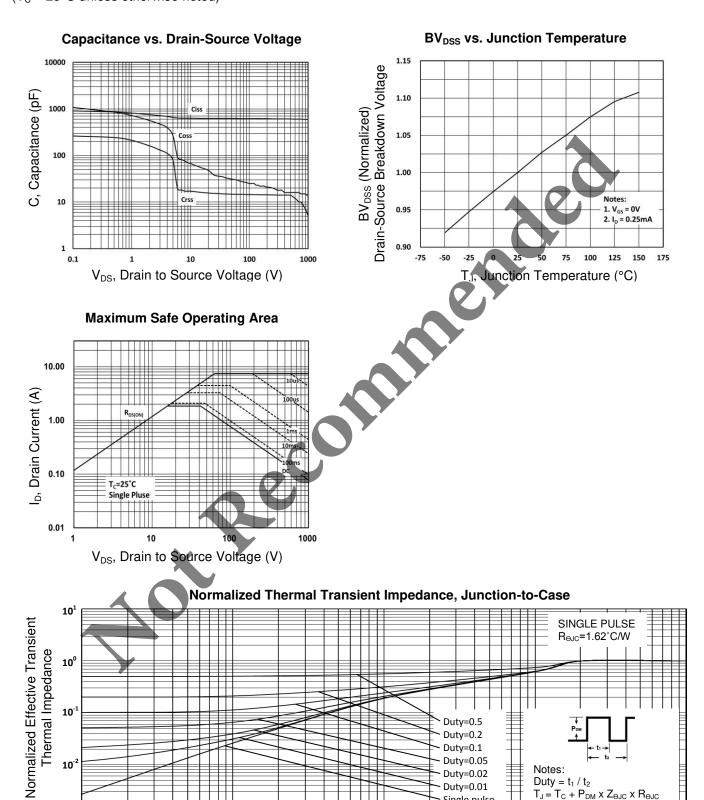
10⁻³

10

10-4

CHARACTERISTICS CURVES

 $(T_C = 25^{\circ}C \text{ unless otherwise noted})$



Version: A1608

10⁻²

10-1

Single pulse

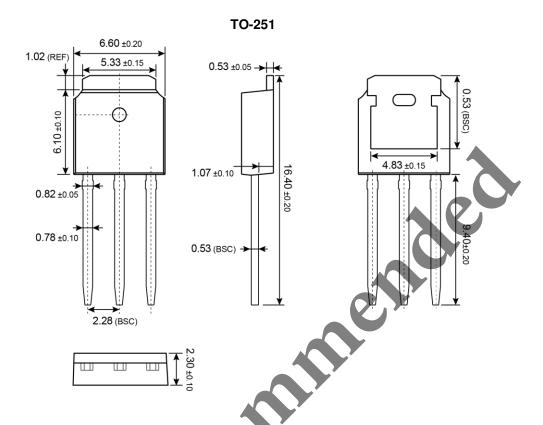
10⁻³

Square Wave Pulse Duration (s)

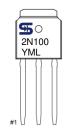
4



PACKAGE OUTLINE DIMENSIONS (Unit: Millimeters)



MARKING DIAGRAM



Y = Year Code

M = Month Code

O =Jan

=Feb

X =Oct

Q =Mar R =Apr

Y =Nov

T =Jun **S ►**May

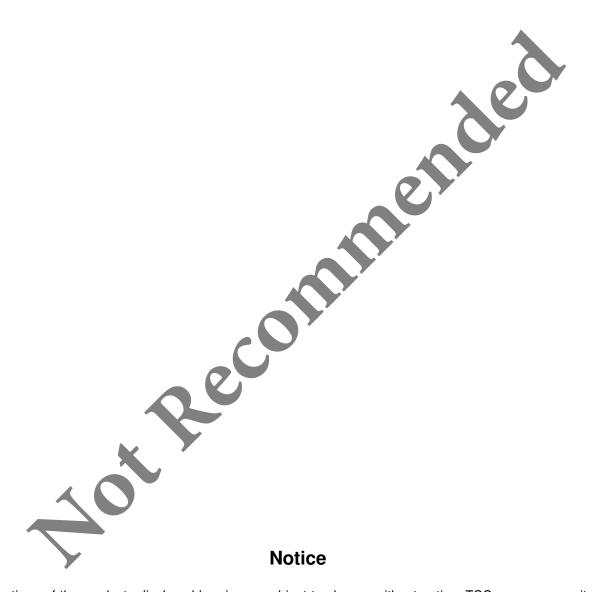
U =Jul V =Aug

5

Z =Dec

Lot Code (1~9, A~Z)





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